

# High-reliability discrete products and engineering services since 1977

## T6411 SERIES

### BIDIRECTIONAL TRIODE THYRISTORS

### **FEATURES**

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Repetitive peak off-stage voltage, gate open			
$(T_J = -65 \text{ to } +100^{\circ}\text{C})$			
T6411B	V <sub>DRM</sub>	200	Volts
T6411D	<b>V</b> DRM	400	Voits
T6411M		600	
T6411N		800	
<b>RMS on-state current</b> (conduction angle = $360^{\circ}$ , $T_C \le 65^{\circ}$ C)	I <sub>T(RMS)</sub>	30	Amps
Peak non-repetitive surge current (One Cycle, 60Hz)	I <sub>TSM</sub>	300	Amps
Circuit fusing considerations	l <sup>2</sup> t		A <sup>2</sup> s
(T <sub>J</sub> = -65 to +100°C, t = 1.25 to 10ms)	I t	450	AS
<b>Peak gate power</b> (pulse width = 1.0μs)	P <sub>GM</sub>	40	Watts
Average gate power	$P_{G(AV)}$	0.75	Watts
Peak gate current (pulse width ≤ 1.0μs)	I <sub>GM</sub>	2	Amps
Operating junction temperature range	T <sub>J</sub>	-65 to +100	°C
Storage temperature range	T <sub>stg</sub>	-65 to +150	°C
Stud torque		30	In. lb.

### THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal resistance, junction to case	R <sub>eJC</sub>	0.9	°C/W

### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C and either polarity of MT2 to MT1 voltage, unless otherwise noted)

Characteristic		Min	Тур	Max	Unit
Peak off state current (V <sub>D</sub> = V <sub>DRM</sub> , gate open, T <sub>J</sub> = 100°C	I <sub>DRM</sub>	-	-	4	mA
Peak on-state voltage (either direction) (I <sub>TM</sub> = 100A peak)		-	2.1	2.5	Volts
DC gate trigger current (continuous dc) $(V_D=12V,R_L=30\Omega)$ $MT2(+),G(+);MT2(-),G(-)$ $MT2(+),G(-);MT2(-),G(+)$	I <sub>GT</sub>	-	20 35	50 80	mA
DC gate trigger voltage (continuous dc), all trigger modes $(V_D=12V,R_L=30\Omega) \\ (V_D=RatedV_{DRM},R_L=125\Omega,T_C=100^{\circ}C)$	V <sub>GT</sub>	- 0.2	1.35 -	2.5	Volts
Holding current $(V_D = 12V, \text{ gate open, } I_T = 150\text{mA})$	I <sub>H</sub>	-	-	60	mA
Gate controlled turn on time $(V_D = Rated \ V_{DRM}, \ I_{TM} = 45A, \ I_{GT} = 200mA, \ rise \ time = 0.1 \mu s)$	t <sub>gt</sub>	-	1.7	3	μs



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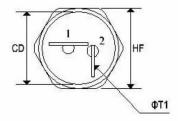
# T6411 SERIES

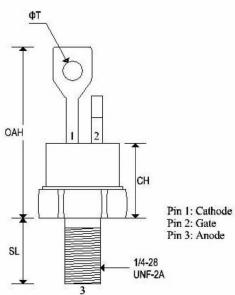
### BIDIRECTIONAL TRIODE THYRISTORS

Critical rate of rise of commutating voltage (commutating di/dt = 16A/ms, gate unenergized, $V_D$ = Rated $V_{DRM}$ , $I_{T(RMS)}$ = 30A, $T_C$ = rated value from figure 1)	dv/dt(c)	3	20	-	V/µs
Critical rate of rise of off-state voltage $(V_D = \text{Rated } V_{DRM}, \text{ gate open, exponential waveform, } T_C = 100^{\circ}\text{C})$					
T6411B	dv/dt	40			V/µs
T6411D		25	-	-	
T6411M		20			

### **MECHANICAL CHARACTERISTICS**

Case	TO-48	
Marking	Alpha-numeric	
Polarity	Cathode is stud	





	TO-48			
	Inches		Millin	neters
	Min	Max	Min	Max
CD	-	0.543	-	13.793
СН	-	0.550	-	13.970
HF	0.544	0.563	13.817	14.301
OAH	-	1.193	-	30.303
SL	0.422	0.453	10.718	11.507
ΦТ	0.125	0.165	3.175	4.191
ΦT <sub>1</sub>	0.060	0.075	1.524	1.905

Note: Contour and angular orientation of terminals 1 and 2 with respect to hex portion and to each other are optional.

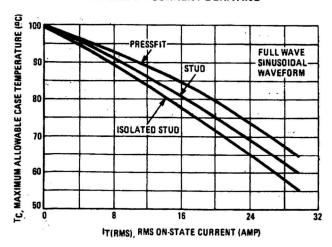


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### BIDIRECTIONAL TRIODE THYRISTORS

#### FIGURE 1 - CURRENT DERATING



#### FIGURE 2 - POWER DISSIPATION

